

N-Channel NexFET™ Power MOSFET

FEATURES

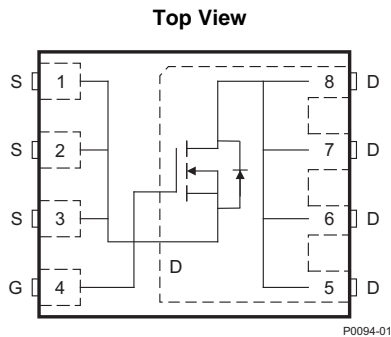
- **Ultralow Q_g and Q_{gd}**
- **Low Thermal Resistance**
- **Avalanche Rated**
- **SON 5-mm × 6-mm Plastic Package**

APPLICATIONS

- **Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems**
- **Optimized for Control FET Applications**

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.



PRODUCT SUMMARY

V_{DS}	Drain-to-source voltage	25	V
Q_g	Gate charge, total (4.5 V)	6.7	nC
Q_{gd}	Gate charge, gate-to-drain	1.9	nC
$r_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}$	5.4 mΩ
		$V_{GS} = 10\text{ V}$	3.6 mΩ
$V_{GS(th)}$	Threshold voltage	1.8	V

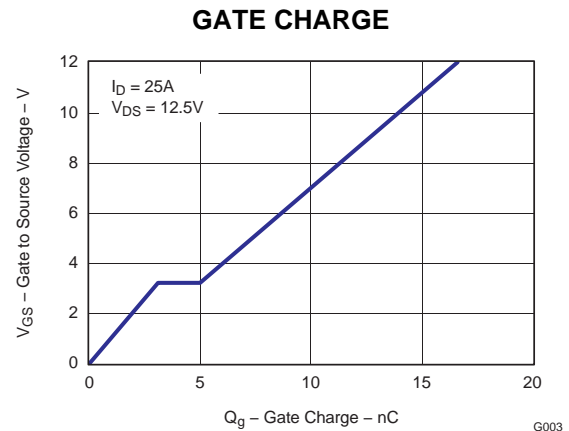
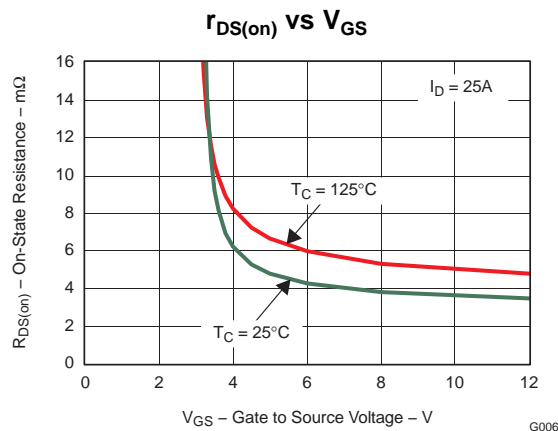
ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16408Q5	SON 5-mm × 6-mm plastic package	13-inch (33-cm) reel	2500	Tape and reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain-to-source voltage	25	V
V_{GS}	Gate-to-source voltage	–12 to 16	V
I_D	Continuous drain current, $T_C = 25^\circ\text{C}$	113	A
	Continuous drain current ⁽¹⁾	22	A
I_{DM}	Pulsed drain current, $T_A = 25^\circ\text{C}$ ⁽²⁾	141	A
P_D	Power dissipation ⁽¹⁾	3.1	W
T_J , T_{STG}	Operating junction and storage temperature range	–55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche energy, single-pulse $I_D = 23\text{ A}$, $L = 0.1\text{ mH}$, $R_G = 25\text{ }\Omega$	126	mJ

- (1) Typical $R_{\theta JA} = 41^\circ\text{C/W}$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$



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ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ unless otherwise stated

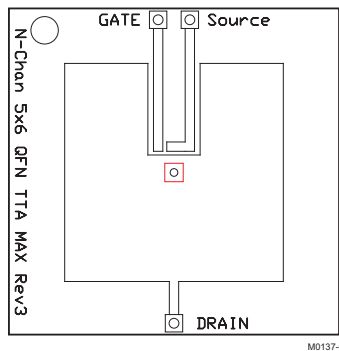
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	25			V
I _{DSS}	Drain-to-source leakage	V _{GS} = 0 V, V _{DS} = 20 V	1			μA
I _{GSS}	Gate-to-source leakage	V _{DS} = 0 V, V _{GS} = −12 V to 16 V	100			nA
V _{GS(th)}	Gate-to-source threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	1.4	1.8	2.1	V
r _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 4.5 V, I _D = 25 A	5.4		6.8	mΩ
		V _{GS} = 10 V, I _D = 25 A	3.6		4.5	mΩ
g _{fs}	Transconductance	V _{DS} = 15 V, I _D = 25 A	60			S
Dynamic Characteristics						
C _{ISS}	Input capacitance	V _{GS} = 0 V, V _{DS} = 12.5 V , f = 1 MHz	990		1300	pF
C _{OSS}	Output capacitance		760		1000	pF
C _{RSS}	Reverse transfer capacitance		75		100	pF
R _g	Series gate resistance		0.8		1.6	Ω
Q _g	Gate charge total (4.5 V)	V _{DS} = 12.5 V, I _D = 25 A	6.7		8.9	nC
Q _{gd}	Gate charge, gate-to-drain		1.9			nC
Q _{gs}	Gate charge, gate-to-source		3.1			nC
Q _{g(th)}	Gate charge at V _{th}		1.8			nC
Q _{OSS}	Output charge	V _{DS} = 13 V, V _{GS} = 0 V	15.7			nC
t _{d(on)}	Turnon delay time	V _{DS} = 12.5 V, V _{GS} = 4.5 V, I _D = 20 A, R _G = 2 Ω	11.3			ns
t _r	Rise time		25			ns
t _{d(off)}	Turnoff delay time		11			ns
t _f	Fall time		10.8			ns
Diode Characteristics						
V _{SD}	Diode forward voltage	I _S = 25 A, V _{GS} = 0 V	0.8		1	V
Q _{rr}	Reverse recovery charge	V _{DD} = 13 V, I _F = 2 5A, di/dt = 300 A/μs	17			nC
t _{rr}	Reverse recovery time	V _{DD} = 13 V, I _F = 25 A, di/dt = 300 A/μs	21			ns

THERMAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ unless otherwise stated

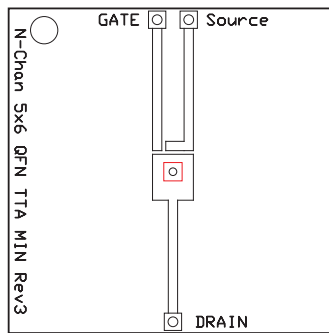
PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			1.9	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ^{(1) (2)}			51	$^\circ\text{C}/\text{W}$

- (1) $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch \times 1.5-inch (3.81-cm \times 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



M0137-01

Max $R_{\theta JA} = 51^{\circ}\text{C/W}$
when mounted on
1 inch² (6.45 cm²) of
2-oz. (0.071-mm thick)
Cu.

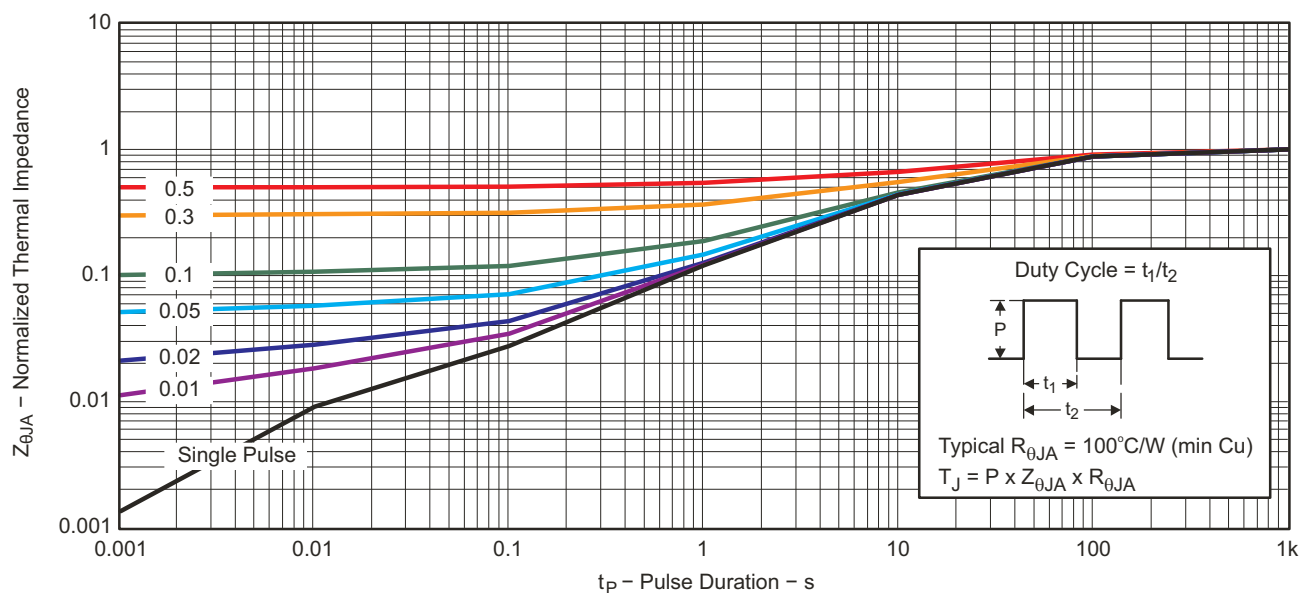


M0137-02

Max $R_{\theta JA} = 125^{\circ}\text{C/W}$
when mounted on
minimum pad area of
2-oz. (0.071-mm thick)
Cu.

TYPICAL MOSFET CHARACTERISTICS

$T_A = 25^{\circ}\text{C}$ unless otherwise stated



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Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ unless otherwise stated

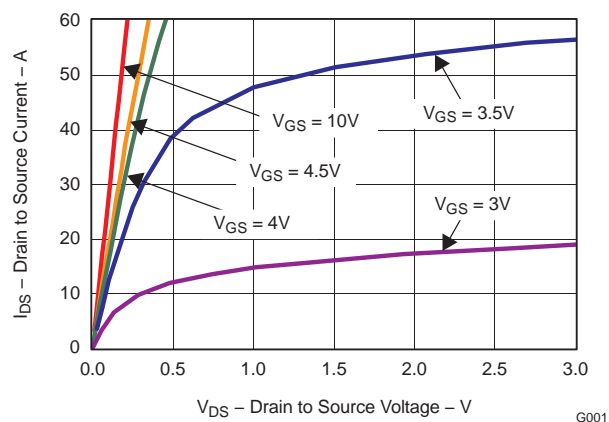


Figure 2. Saturation Characteristics

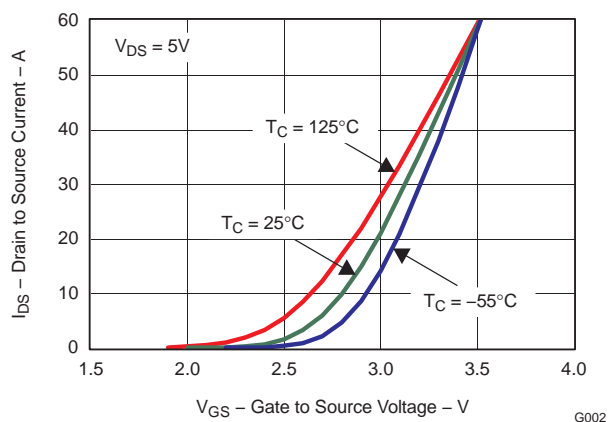


Figure 3. Transfer Characteristics

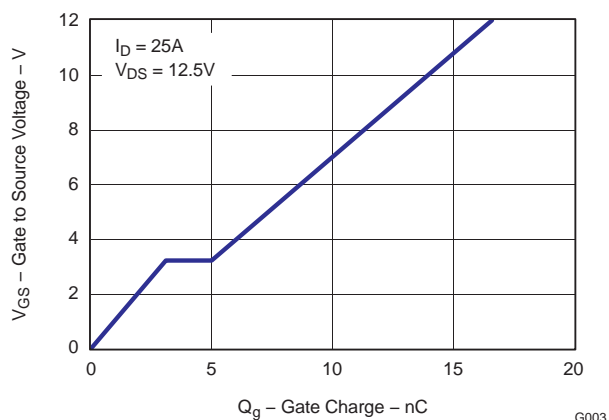


Figure 4. Gate Charge

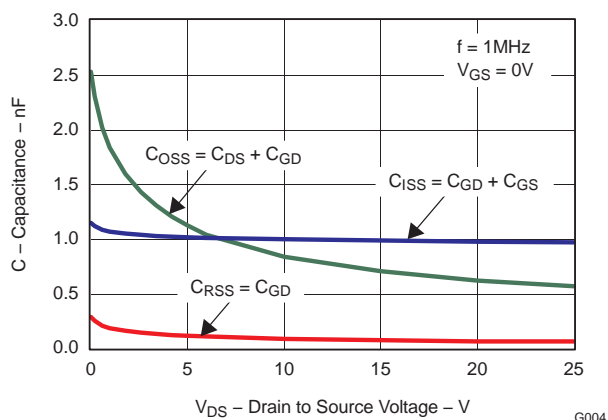


Figure 5. Capacitance

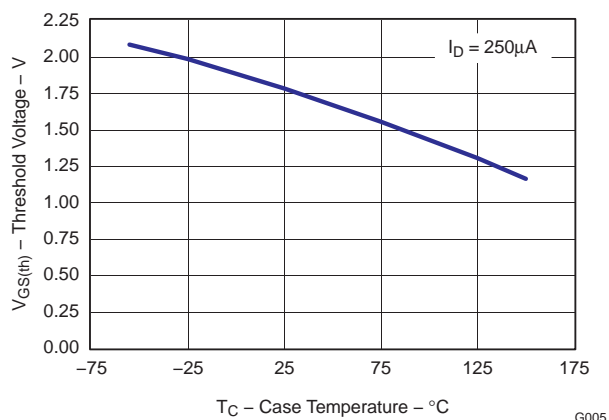


Figure 6. Threshold Voltage vs. Temperature

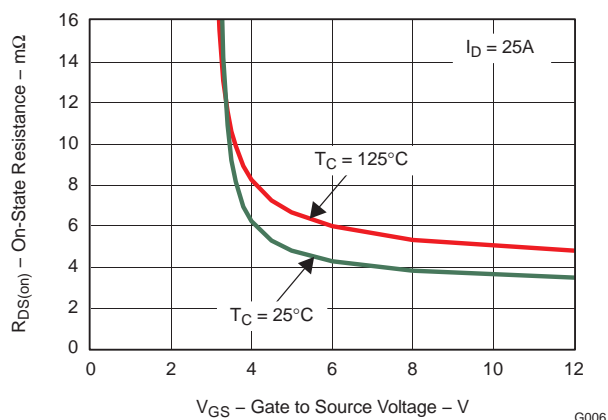


Figure 7. On-State Resistance vs. Gate-to-Source Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ unless otherwise stated

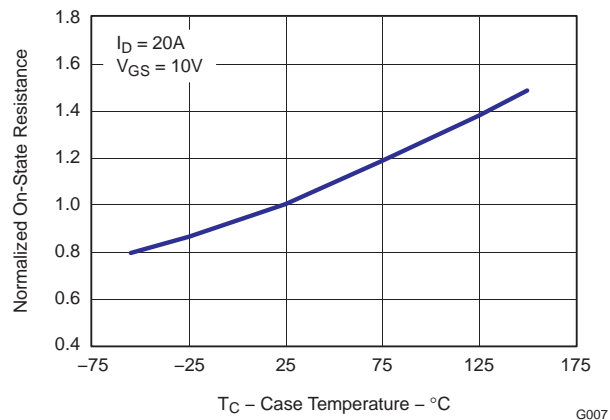


Figure 8. Normalized On-State Resistance vs. Temperature

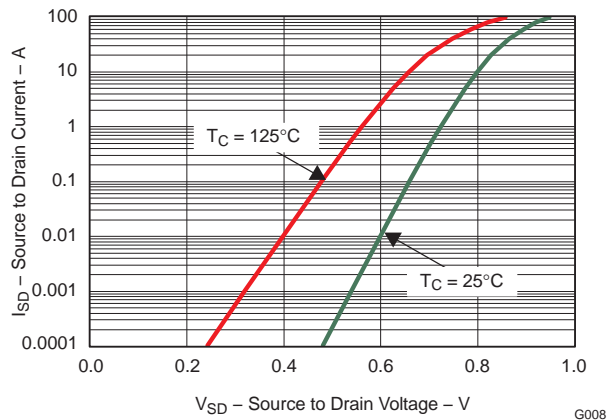


Figure 9. Typical Diode Forward Voltage

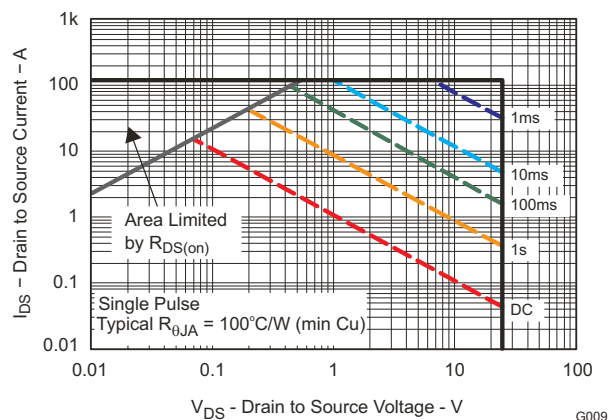


Figure 10. Maximum Safe Operating Area

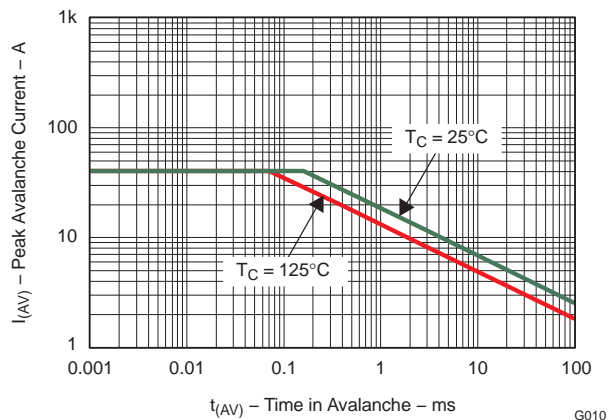


Figure 11. Single-Pulse Unclamped Inductive Switching

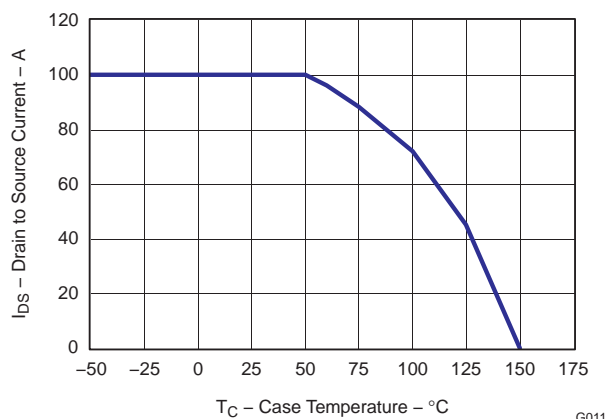
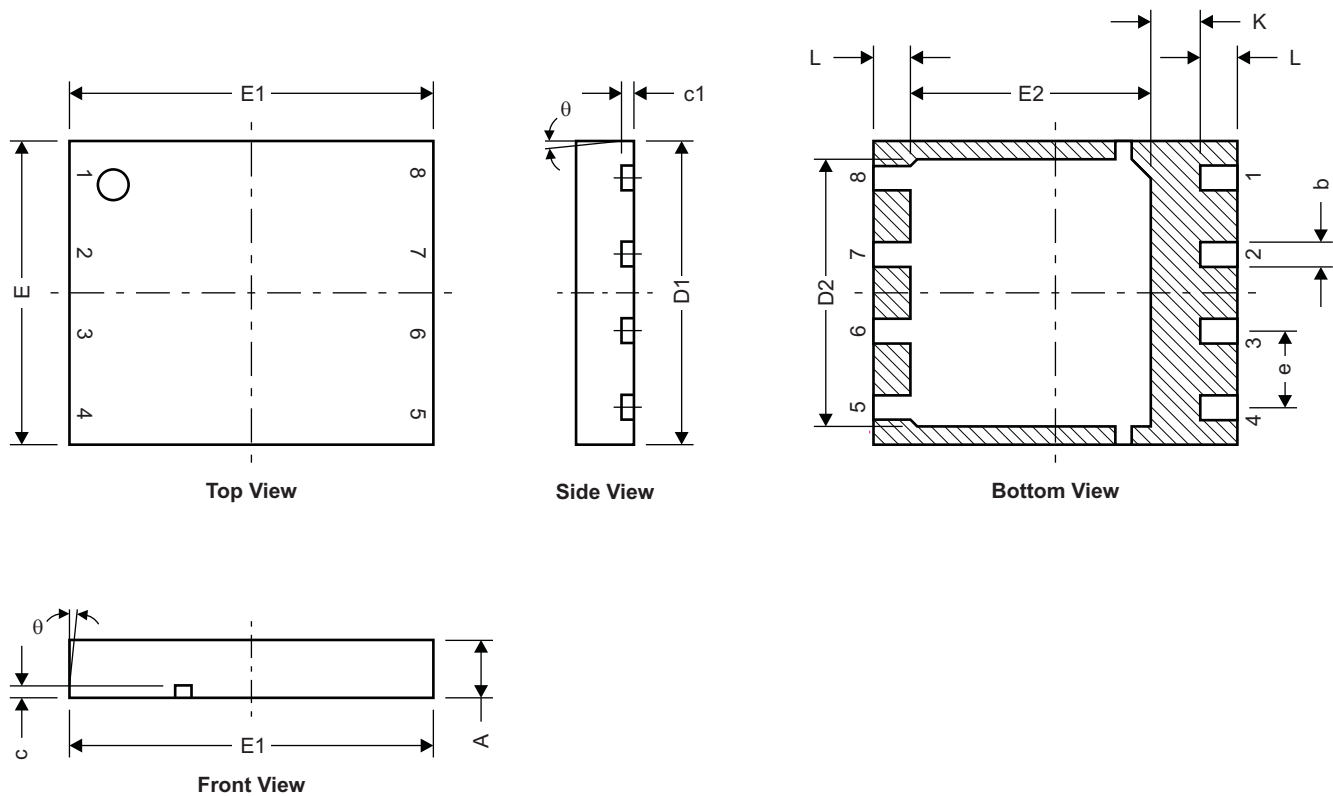


Figure 12. Maximum Drain Current vs. Temperature

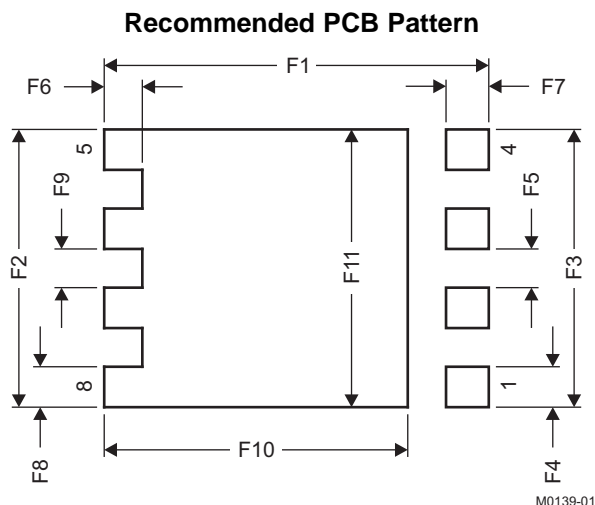
MECHANICAL DATA

Q5 Package Dimensions



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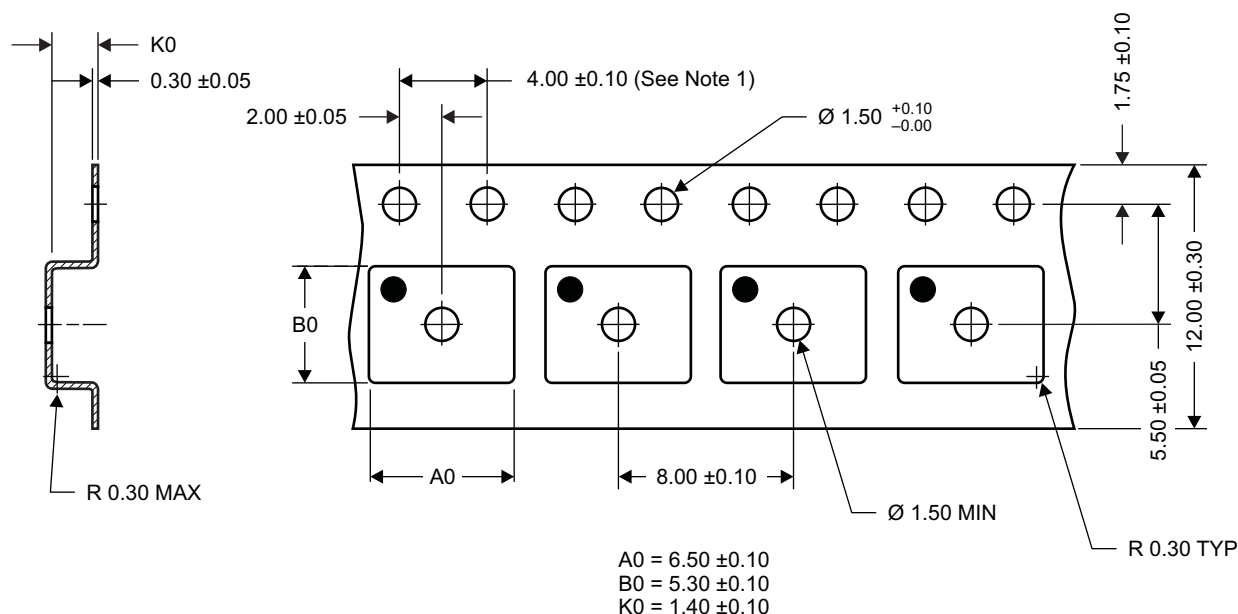
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 typ		0.050	
L	0.510	0.710	0.020	0.028
θ	0.00	—	—	—



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note *Reducing Ringing Through PCB Layout Techniques* (SLPA005).

Q5 Tape and Reel Information



Notes:

- 10-sprocket hole-pitch cumulative tolerance ± 0.2
- Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- Material: black static-dissipative polystyrene
- All dimensions are in mm, unless otherwise specified.
- A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket
- MSL1 260°C (IR and convection) PbF reflow compatible

REVISION HISTORY

Changes from Revision Original (October 2009) to Revision A	Page
• Deleted environmental bullets from features list	1
• Deleted package marking section from end of data sheet	7

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD16408Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16408	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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